



TO-92 Plastic-Encapsulate Transistors

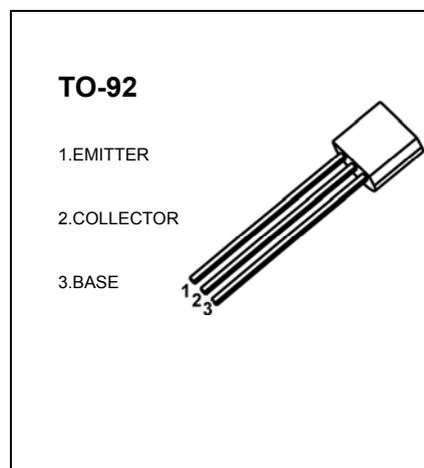
C1815 TRANSISTOR (NPN)

FEATURES

Power dissipation

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|------------------|---|----------|------|
| V _{CB0} | Collector-Base Voltage | 60 | V |
| V _{CEO} | Collector-Emitter Voltage | 50 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current -Continuous | 150 | mA |
| P _C | Collector Power Dissipation | 400 | mW |
| R _{θJA} | Thermal Resistance from Junction to Ambient | 312 | °C/W |
| T _J | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature | -55~+150 | °C |



ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

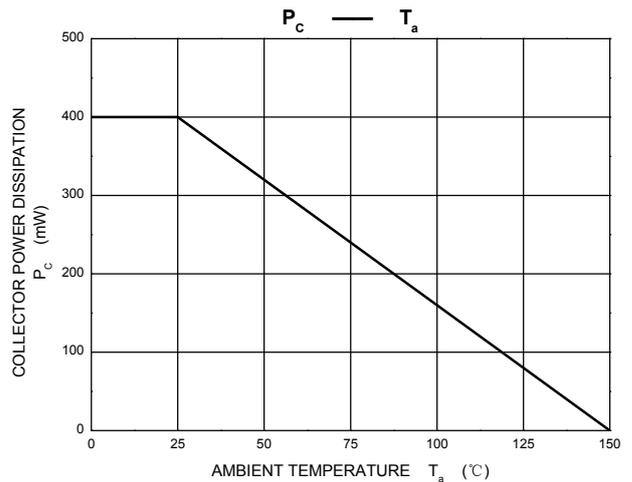
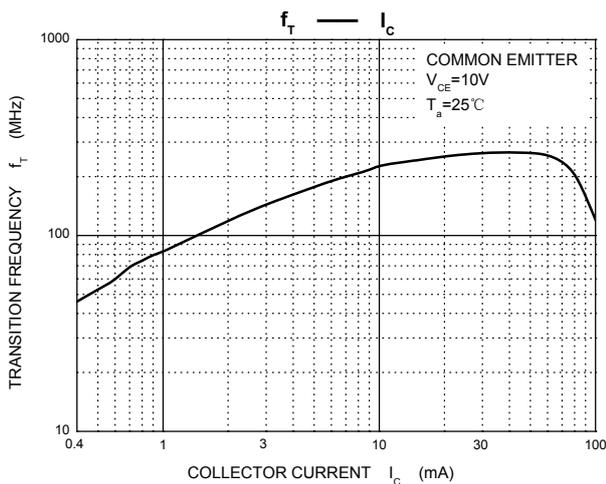
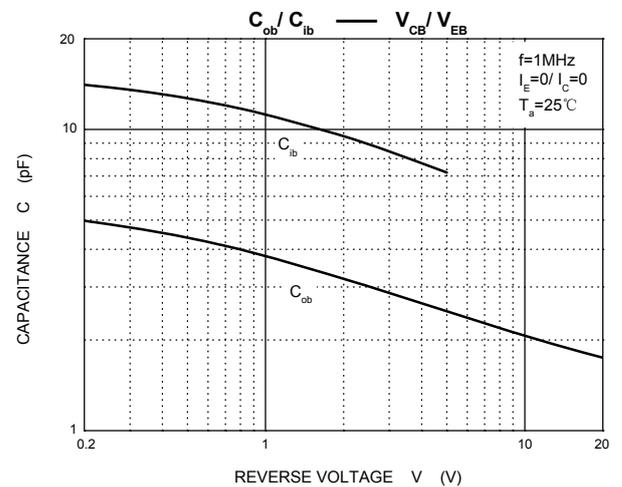
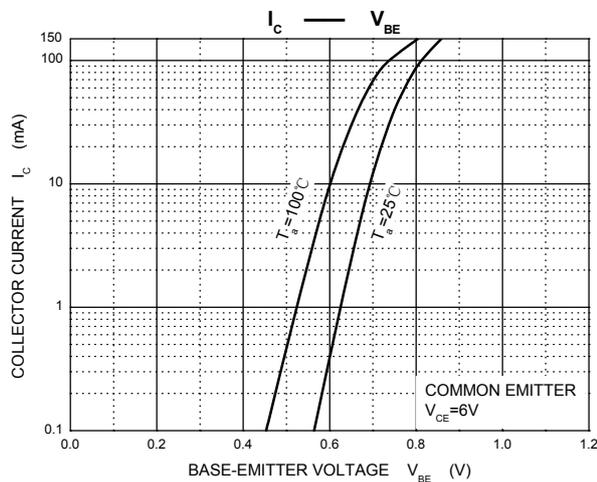
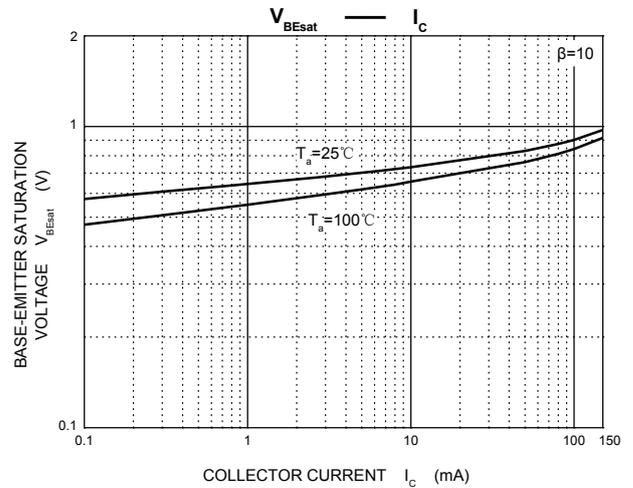
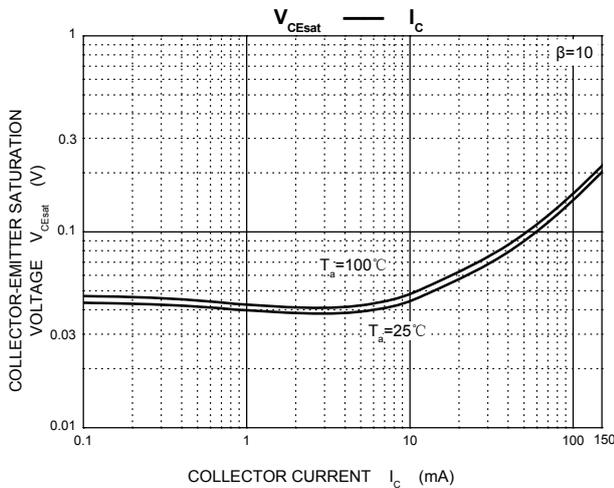
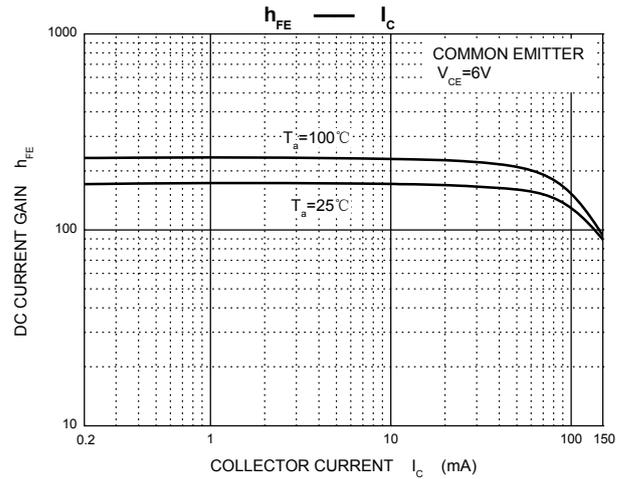
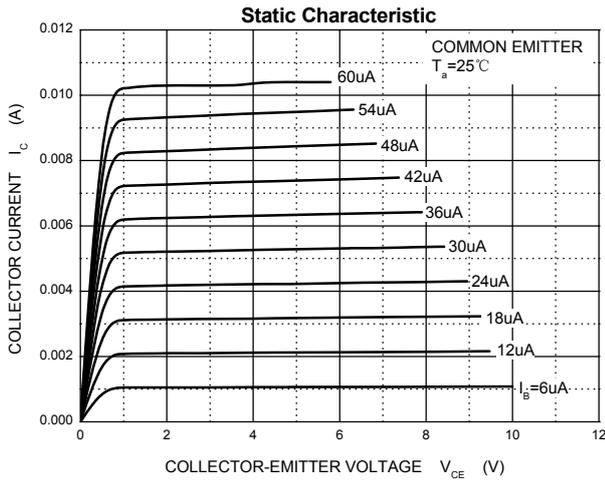
| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|--------------------------------------|----------------------|--|-----|-----|------|------|
| Collector-base breakdown voltage | V _{(BR)CBO} | I _C = 100uA, I _E =0 | 60 | | | V |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | I _C = 0.1mA, I _B =0 | 50 | | | V |
| Emitter-base breakdown voltage | V _{(BR)EBO} | I _E = 100uA, I _C =0 | 5 | | | V |
| Collector cut-off current | I _{CB0} | V _{CB} = 60V, I _E =0 | | | 0.1 | uA |
| Collector cut-off current | I _{CEO} | V _{CE} = 50V, I _B =0 | | | 0.1 | uA |
| Emitter cut-off current | I _{EBO} | V _{EB} =5V, I _C =0 | | | 0.1 | uA |
| DC current gain | h _{FE} | V _{CE} = 6 V, I _C = 2mA | 70 | | 700 | |
| Collector-emitter saturation voltage | V _{CE(sat)} | I _C =100mA, I _B =10mA | | | 0.25 | V |
| Base-emitter saturation voltage | V _{BE(sat)} | I _C =100mA, I _B =10mA | | | 1 | V |
| Transition frequency | f _T | V _{CE} =10 V, I _C = 1mA f=30MHz | 80 | | | MHz |
| Collector Output Capacitance | C _{ob} | V _{CB} =10V, I _E =0 f=1MHz | | | 3.5 | pF |
| Noise Figure | NF | V _{CE} =6V, I _C =0.1mA f =1KHz, R _G =10K | | | 10 | dB |

CLASSIFICATION OF h_{FE}

| Rank | O | Y | GR | BL |
|-------|--------|---------|---------|---------|
| Range | 70-140 | 120-240 | 200-400 | 350-700 |

Typical Characteristics

C1815



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